








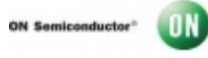
	<h2 style="color: red;">NTP5426NG</h2>
	<p>Hersteller-Teilenummer: NTP5426NG</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 60V 120A TO-220AB</p> <hr/> <p>Datenblätter:  NTP5426NG.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 17388 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTP5426NG
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 120A TO-220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	17388 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	215W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	120A (Tc)
Rds On (Max) @ Id, Vgs	6 mOhm @ 60A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	170nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	5800pF @ 25V
Verpackung	Tube



















































NTP5426NG ist neu im Original, Suche NTP5426NG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTP5426NG AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTP5426NG: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTP5860NL O NTP5860NL O</p>	 <p>NTP5411NG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 80A TO-220AB</p>	 <p>NTP5860NLG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 220A TO-220-3</p>	 <p>NTP5426N AMI Semiconductor / ON Semiconductor NTP5426N ON</p>
 <p>NTP5862NG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V TO-220-3</p>	 <p>NTP5860N VB NTP5860N VB</p>	 <p>NTP5404NRG AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 136A TO220AB</p>	 <p>NTP5404N AMI Semiconductor / ON Semiconductor NTP5404N ON</p>

heiße Teile

Mehr

 NTP18N06LG	 NTP22N06	 NTP22N06L	 NTP27N06G	 NTP27N06L
 NTP2955G	 NTP30N06L	 NTP30N06LG	 NTP30N20	 NTP30N20G
 NTP35N15	 NTP35N15G	 NTP4302G	 NTP45N06	 NTP45N06G
 NTP45N06L	 NTP45N06LG	 NTP477M04TDR	 NTP52N10	 NTP52N10G
 NTP5404N	 NTP5404NRG	 NTP5411NG	 NTP5412NG	 NTP5426N
 NTP5860N	 NTP5860NG	 NTP5860NL	 NTP5860NLG	 NTP5862NG
 NTP5863N	 NTP5863NG	 NTP5864N	 NTP5864NG	 NTP60N06
 NTP60N06G	 NTP60N06L	 NTP60N06LG	 NTP6410AN	 NTP6410ANG
 NTP6411AN	 NTP6411ANG	 NTP6412AN	 NTP6412ANG	 NTP6413AN
 NTP6413ANG	 NTP6448ANG	 NTP65N02R	 NTP65N02RG	 NTP75N03-006

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